Partial Discharge Pattern of Various Defects Measured by Spiral Antenna as UHF External Sensor on 66 kV GIS Model

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Abstract: This paper deals with partial discharge (PD) measurement in gas insulated switchgear (GIS) using spiral antenna as UHF external sensor. PD detection in UHF band is effective because it detects electromagnetic (EM) wave induced by PD with high S/N ratio. External sensor was used to detect leaked EM wave signals from insulation spacer of GIS tank. The experiment was conducted in 66 kV GIS model with metal type spacer. There is insulation window in the spacer. PD was generated by some artificial defects in GIS and an external PD source. The leaked EM wave propagated through spacer aperture was measured using spiral type sensor without filter and amplifier. The peak to peak value (Vpp) and the transmission rate of electromagnetic wave signals were evaluated. The PD patterns were observed. The results showed that the PD was detected by the spiral antenna. PD pattern was unique for each defect. These results are considered to be useful for enhancement of database PD diagnosis.

Keywords – partial discharge, external sensor, spiral antenna, UHF detection, PD pattern

1. Introduction
Detection of partial discharge (PD) is useful for condition monitoring of gas insulated switchgear (GIS) [1-8]. For the insulation diagnosis of GIS, the ultra-high frequency (UHF) method which detects PD induced electromagnetic wave (EM-wave) in the UHF band (300 MHz to several GHz) with little noise influence, has rapidly developed in recent years [9-18]. It is necessary to install a sensor inside or set on the outside of a GIS tank to detect partial discharge (PD) signals that propagate inside a GIS. For GISs that have already been constructed, it is effective to use external diagnosis using EM-wave signals that radiate (leak) from the insulation spacer of the GIS tank [19]. For a metal spacer, there is usually an insulation aperture in the spacer which enables EM-wave to radiate. Some external sensors for PD detection in GIS have been examined recently such as bowtie antenna, horn antenna, and loop antenna [20-30].

In this research the spiral antenna was examined to measure PD in 66 kV GIS model. PD was generated by some artificial PD sources; those are protrusion on the high voltage conductor, protrusion on the tank, floating electrode, free particle, void, particle on the spacer, and aerial/external defects. PD pattern was measured by spiral antenna as UHF sensors and observed by PD monitoring device. These results are considered to be useful for enhancement of database PD diagnosis.

2. Experimental Setup
A. GIS Model
The experimental setup was arranged as shown in Figure 1. The 66 kV GIS model was used in the experiment. GIS 66 kV structure is composed of coaxial cylindrical electrodes with high voltage conductors and insulating spacers. The GIS central conductor is 80 mm in diameter and GIS tank was 200 mm in diameter. Each gas section is 1000 mm in length, except for the end

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conductor with connected gas compartment with total length is 1500 mm. The insulating spacer is made from epoxy resin with a cone-shaped structure (relative dielectric constant = 4). The outer periphery of the insulating spacer is clad with aluminium and part of the epoxy resin is exposed bare. The exposed part of the epoxy resin (spacer aperture) is 65 mm in length and 15 mm width. The gas compartment was filled with SF₆ gas at 0.15 MPa.

B. PD charge calibration

Before the main experiment, the charge calibration was conducted using a pulse calibrator as shown in Figure 2. The charge was injected from a pulse calibrator into GIS bushing and the output was measured by an oscilloscope. The charge calibration results are shown in Figure 3. The PD apparent charge can be estimated when the voltage measured using CD6 based on the conventional method (IEC 60270) is known.

Figure 1. Experimental setup and condition

Figure 2. Charge calibration of experimental setup
C. Spiral Antenna as UHF PD Sensor

The leaked EM wave propagated through spacer aperture was measured using spiral type sensor. For PD pattern measurement, three spiral antennas as UHF sensors (named as A, B, C) placed on the aperture spacer. The sensors were connected to the channel switch as a power supply. The output of the channel switch was connected to PDM device and the oscilloscope and the computer. The envelope processing and amplification were processed in PDM device. The PD pattern was observed and recorded in the computer.

For transmission rate evaluation, two spiral sensors without envelope processing & amplifier (called as original sensor) connected to spacer A and spacer B. The sensors were connected to an oscilloscope (oscilloscope Tektronix, DPO4104, 1 GHz, 5 GS/s). The PD detecting device (CD-6) based on conventional method IEC 60270 was used as comparison. We used limit resistance 200 kΩ, coupling capacitor 2 nF, and RC detection impedance (R constant = 50 ohm and C variable = 470 pF).

The voltage was converted into apparent charge based on the calibration result using the charge calibrator. Partial discharge was measured using partial discharge monitoring (PDM) device, oscilloscope voltage / current-time graph, and conventional method IEC 60270.

D. Artificial PD Source

Figure 4 shows seven artificial defects used in this experiment. Those are: protrusion on the high voltage conductor (POC), protrusion on the tank (POT), floating electrode (FLOATING), free metal particle (FMP), particle on the spacer (POS), void / delamination (DEL) and aerial defect (OUTSIDE).

Protrusion on the high voltage conductor (HVC) is a 5 cm needle electrode (Ogura) attached on the conductor. The curvature of the needle tip was 30°. The gap between the needle tip and the tank was 1 cm. PDIV from above configuration was 6 kV. Protrusion on the tank was made similar with protrusion on the high voltage conductor. PDIV from protrusion on the tank was 11 kV.

Floating electrode defect made from steel with 20 mm in length was floating in SF6 gas by being tied to a piece of string attached to the side walls of the tank. The gap length between the conductor and the tip of maximum position of floating electrode was 5 mm. PDIV for this model was 23 kV.

Two free metal particle defects made from steel with length 1 cm was attached to both end of a 12 cm string adhered in middle to the side wall. PDIV for this model was 15 kV.

Particle on the spacer is made from steel adhered to the top side of the spacer. The length of steel was 1 cm with the gap between the conductor and the spacer was 1 cm. We placed a piece of spacer on the bottom side of tank with 5 cm in height. PDIV for this model was 45 kV.
Void / delamination defect is made from resin with 0.3 mm air gap. The length of void was 3 mm. We placed the resin connected to the conductor on the topside and grounded to the tank on the bottom side.

Aerial outside defect made from needle-plane electrode with gap 1 mm was directly connected to GIS. PDIV from this model was 3 kV.
3. Experimental Results

Partial discharges are represented by several parameters: PD inception voltage ($V_i$) in [kV], phase angle of PD occurrence and PD number or PD frequency in a specific time or phase angle. Figures 5-11 show PD emitted EM waveform from the various defects.

Figure 5. PD induced EM waveform from protrusion on high voltage conductor measured by external sensors in 66 kV GIS model
Figure 6. PD induced EM waveform from protrusion on the tank measured by external sensors in 66 kV GIS model

Figure 7. PD induced EM waveform from floating electrode measured by external sensors in 66 kV GIS model

Figure 8. PD induced EM waveform from free metal particle measured by external sensors in 66 kV GIS model
Figure 9. PD induced EM waveform from particle on the spacer measured by external sensors in 66 kV GIS model

Figure 10. PD induced EM waveform from aerial defect (PD source outside GIS) measured by external sensors in 66 kV GIS model

Figure 11 PD induced EM waveform from delamination model measured by external sensors in 66 kV GIS model
Figures 12-18 show PRPD pattern measured by external spiral type antenna sensor.

Figure 12. PD Pattern of protrusion on HVC measured by external sensors with spiral antenna in 66 kV GIS

Figure 13. PD Pattern of protrusion on the tank measured by external sensors with spiral antenna in 66 kV GIS

Figure 14. PD Pattern of floating electrode measured by external sensors with spiral antenna in 66 kV GIS
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Figure 15. PD Pattern of Free metal particle measured by external sensors with spiral antenna in 66 kV GIS

Figure 16. PD Pattern of Particle on spacer measured by external sensors with spiral antenna in 66 kV GIS

Figure 17. PD Pattern of Aerial Defects measured by external sensors with spiral antenna in 66 kV GIS
4. ANALYSIS & DISCUSSION

A. Phase Resolved PD Pattern

The experiment results are analyzed and discussed based on statistical approach, trending, and graph or table. First we examined PRPD pattern data. PRPD patterns presented here were recorded in uni-polar mode with time of acquisition of 120 seconds. Characteristics of PD for pattern recognition and classification are computed from the relation of the voltage phase angle, the discharge magnitude and the repeated existing of PD using statistical analysis. The PD quantity as function of the phase angle represent the recurrence of PD related to their phase angle [31-33]. The voltage cycle is divided into phase window representing the angle axis (0–360°). The four quantities can be determined in each phase window as follows:

1. The sum of the discharge magnitudes observed in one phase window (discharge amount).
2. The number of discharges observed in one phase window (pulse count).
3. The average value of discharges observed in one phase (mean pulse height).
4. The maximum value of discharge observed in one phase window (maximum pulse height).

Table 1 summarizes the specific PD occurrence phase angle of each artificial defect. Protrusion on high voltage conductor (POC) defect shows that discharges pulses occurred in negative half cycles. The discharges were concentrated around the peak of the negative half cycle of the applied voltage which indicated that the discharges occurrence was mainly influenced by the instantaneous applied voltage. This phenomenon was due to the availability of initial electrons which were easily ejected from needle tip to initiate negative discharges.

<table>
<thead>
<tr>
<th>Discharges / Defect</th>
<th>Specific Phase</th>
</tr>
</thead>
<tbody>
<tr>
<td>Protrusion on HVC (POC)</td>
<td>270°</td>
</tr>
<tr>
<td>Protrusion on Tank (POT)</td>
<td>90°</td>
</tr>
<tr>
<td>Floating electrode (FLOATING)</td>
<td>225°; 45°</td>
</tr>
<tr>
<td>Free metal particle (FMP)</td>
<td>Randomly</td>
</tr>
<tr>
<td>Particle on spacer (POS)</td>
<td>45°; 225°</td>
</tr>
<tr>
<td>Void / delamination (DEL)</td>
<td>0°; 180°</td>
</tr>
<tr>
<td>Aerial / GIS outside (OUTSIDE)</td>
<td>67.5°</td>
</tr>
</tbody>
</table>
Protrusion on tank (POT) defect shows that discharges pulses occurred in positive half cycles. It is also influenced by instantaneous applied voltage because positive ions on HV conductor side affect the appearance of negative ion (electron) on the ground side (tank). Then, initial electrons are ejected from needle tip to initiate discharges.

Floating electrode (FLOATING) defect shows that discharges pulses occurred in 225° and 45°. It indicates that discharges occurred under voltage rise and fall (time derivative of applied voltage dv/dt is positive on the left side and negative on the right side). This indicates that discharge occurrence depends on the slope/gradient of the applied voltage.

Free metal particle (FMP) defect shows that discharges pulses occurred as a random in voltage phase. It indicates that the discharges occurrence influenced by the instantaneous applied voltage. As a free particle, they can behave like a protrusion on the conductor/tank or floating metal. Therefore they have combination pattern from protrusion and floating metal.

Particle on spacer (POS) defect shows that discharges pulses occurred in 45° and 225°. It can be explained that the spacer acts as capacitor in which there are charging and discharging process. Besides that, influence of particle existences give a reason that discharge still depend on instantaneous applied voltage. Therefore they undergo like phase shift because of space charge process and also act as particle.

B. Statistical Characteristic of PD Pattern

Table 2 summarizes statistical characteristics of PD for various defects. \( H_n(\phi) \) represents the number of the observed discharges in each phase window as a function of the phase angle. \( H_{q n}(\phi) \) is mean pulse height distribution which represents the average amplitude in each phase window as a function of phase angle. \( H_{q n \text{ max}}(\phi) \) represents maximum amplitude in each phase window as a function of phase angle.

<table>
<thead>
<tr>
<th>Discharges / Problem</th>
<th>( H_{q n \text{ max}}(\phi) )</th>
<th>( H_{q n \text{ max}}(\phi) )</th>
<th>( H_{q n}(\phi)+ )</th>
<th>( H_{q n}(\phi)- )</th>
<th>( H_{n}(\phi)+ )</th>
<th>( H_{n}(\phi)- )</th>
</tr>
</thead>
<tbody>
<tr>
<td>Protrusion on HVC (POC)</td>
<td>-</td>
<td>240.6</td>
<td>-</td>
<td>117.5</td>
<td>-</td>
<td>185.4</td>
</tr>
<tr>
<td>Protrusion on Tank (POT)</td>
<td>110</td>
<td>22.5</td>
<td>21.8</td>
<td>1.1</td>
<td>154.7</td>
<td>4.2</td>
</tr>
<tr>
<td>Floating electrode (FLOATING)</td>
<td>8.9</td>
<td>11.9</td>
<td>2.1</td>
<td>3.8</td>
<td>5.1</td>
<td>6.7</td>
</tr>
<tr>
<td>Free metal particle (FMP)</td>
<td>11.9</td>
<td>32.1</td>
<td>3.8</td>
<td>4.1</td>
<td>17.4</td>
<td>21.3</td>
</tr>
<tr>
<td>Particle on spacer (POS)</td>
<td>18.2</td>
<td>20.1</td>
<td>2.2</td>
<td>2.3</td>
<td>13.1</td>
<td>14.2</td>
</tr>
<tr>
<td>Void / delamination (DEL)</td>
<td>14.1</td>
<td>14.6</td>
<td>2.9</td>
<td>3.1</td>
<td>19.5</td>
<td>20.4</td>
</tr>
<tr>
<td>Aerial / GIS outside (OUTSIDE)</td>
<td>18.6</td>
<td>4.8</td>
<td>3.5</td>
<td>1.8</td>
<td>20.5</td>
<td>4.7</td>
</tr>
</tbody>
</table>

Table 3 summarizes skewness and kurtosis of PD pattern characteristics for various defects. Skewness is a measure of symmetry, or more precisely, the lack of symmetry. A distribution, or data set, is symmetric if it looks the same to the left and right of the center point. Kurtosis is a measure of whether the data are peaked or flat relative to a normal distribution. That is, data sets with high kurtosis tend to have a distinct peak near the mean, decline rather rapidly, and have heavy tails. Data sets with low kurtosis tend to have a flat top near the mean rather than a sharp peak.
Table 3. Kurtosis & Skewness values from various defects

<table>
<thead>
<tr>
<th></th>
<th>Protrusion on HVC (POC)</th>
<th>Protrusion on Tank (POT)</th>
<th>Free metal particle (FMP)</th>
<th>Particle on spacer (POS)</th>
<th>Void / delamination (DEL)</th>
<th>Aerial / GIS outside (OUTSIDE)</th>
</tr>
</thead>
<tbody>
<tr>
<td>ku+</td>
<td>-</td>
<td>1.1</td>
<td>-0.5</td>
<td>-1.1</td>
<td>2</td>
<td>-1.2</td>
</tr>
<tr>
<td>ku-</td>
<td>-1.1</td>
<td>-</td>
<td>-0.5</td>
<td>-0.5</td>
<td>2</td>
<td>-1.1</td>
</tr>
<tr>
<td>sk+</td>
<td>-</td>
<td>0.1</td>
<td>0</td>
<td>-0.1</td>
<td>-0.2</td>
<td>0.1</td>
</tr>
<tr>
<td>sk-</td>
<td>0.1</td>
<td>-</td>
<td>0</td>
<td>0</td>
<td>0</td>
<td>0.5</td>
</tr>
</tbody>
</table>

It can be concluded that there is tendency kurtosis give positive result for protrusion on the tank defect, aerial defect, and particle on the spacer defect and negative result for the rest. On the other side, there is tendency that skewness of all defects almost give symmetric pattern, so skewness value tend to zero value. It can be explained because of the effect of symmetrical role of the electrode system (i.e needle-ground electrode) in producing discharges.

Figure 19 shows apparent charge from different defects measured based on IEC 60270. It was seen that floating electrode (FL) defect gives the largest apparent charge and followed by aerial defects charge. Floating electrode is not connected into conductor or tank (ground), so they will result in big discharge once exceed the threshold. Free metal particle and particle on spacer defects give small apparent charge. Free metal particle (FMP) defect result small apparent charge due to mobile effect, meanwhile particle on spacer (POS) defect result small apparent charge due to combination between spacer existence and small protrusion. From above explanation, the apparent charge results does not seem to be correlated with UHF measurement.

Figure 19. Apparent charge of various defects measured by partial discharge detection in 66 kV GIS

Figure 20 shows Transmission Rate based on Vpp comparison. The transmission rate ($T_{RB}$) is defined as a comparison between intensity of PD induced electromagnetic wave measured by sensor B (length from PD source = 1.5 m) compare to one measured by sensor A (length from PD source = 0.5 m). The transmission rate ($T_K$) informs attenuation (damping) characteristics because of the spacer presence and the propagation properties. It was obvious from Figure 20 that the average transmission rate is about 70% except floating electrode and aerial defect.
5. Conclusion

We investigated PD pattern from several artificial defects measured with spiral antenna type as the external UHF sensors in 66 kV GIS model. The results showed that PD PRPD Pattern and PD waveform of each defect have their own characteristic that differ from each other. Specific PD phase angle and statistical analysis of each artificial defect results in various characteristics. Floating electrode defect gives the largest apparent charge, the transmission rate of each artificial defect was about 70%. These results are considered to be useful for the enhancement of PD database measured by the external sensor.

6. References

Partial Discharge Pattern of Various Defects Measured by Spiral Antenna


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